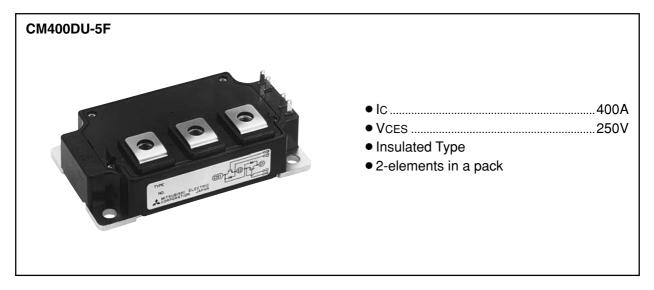
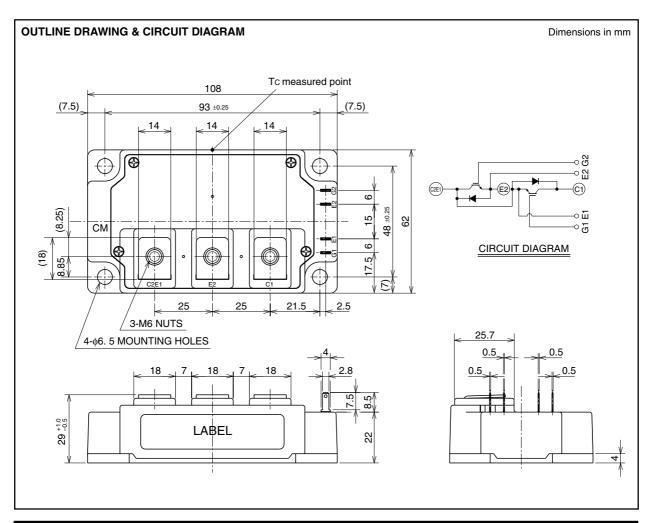
**HIGH POWER SWITCHING USE** 



#### **APPLICATION**

DC choper, Inverters for battery source





#### **HIGH POWER SWITCHING USE**

#### MAXIMUM RATINGS (Tj = 25°C, unless otherwise specified)

Symbol	Parameter	Conditions		Ratings	Unit	
VCES	Collector-emitter voltage	G-E Short		250	V	
VGES	Gate-emitter voltage	C-E Short		±20	V	
Ic	Collector current	Tc = 25°C	400	_ A		
Ісм	Collector current	Pulse (	(Note 2)	800	^	
IE (Note 1)	Emitter current	Tc = 25°C		400	Α	
IEM (Note 1)	Emiller current	Pulse (	(Note 2)	800		
PC (Note 3)	Maximum collector dissipation	Tc = 25°C		890	W	
Tj	Junction temperature			<b>−</b> 40 ~ +150	°C	
Tstg	Storage temperature			<b>−</b> 40 ~ +125	°C	
Viso	Isolation voltage	Terminals to base plate, f = 60Hz, AC 1 minute		2500	Vrms	
_	Torque strength	Main terminals M6 screw		3.5 ~ 4.5	N•m	
		Mounting M6 screw		3.5 ~ 4.5	N•m	
_	Weight	Typical value		400	g	

#### ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise specified)

Cumphal	Parameter	Test conditions		Limits			l lmia
Symbol	Parameter			Min.	Тур.	Max.	Unit
ICES	Collector cutoff current	VCE = VCES, VGE = 0V			_	1	mA
VGE(th)	Gate-emitter threshold voltage	IC = 40mA, VCE = 10V		3.0	4.0	5.0	V
IGES	Gate leakage current	±VGE = VGES, VCE = 0V			_	0.5	μΑ
V05(+)	Collector-emitter saturation voltage	IC = 400A, VGE = 10V	Tj = 25°C		1.2	1.7	V
VCE(sat)			Tj = 125°C	_	1.1	_	
Cies	Input capacitance	VCE = 10V VGE = 0V		_	_	110	nF
Coes	Output capacitance			_	_	7.0	
Cres	Reverse transfer capacitance			_	_	3.8	
QG	Total gate charge	VCC = 100V, IC = 400A, VGE = 10V		_	1500	_	nC
td(on)	Turn-on delay time	Vcc = 100V, Ic = 400A		_	_	850	ns
tr	Turn-on rise time			_	_	400	
td(off)	Turn-off delay time	VGE = ±10V	_	_	1100		
tf	Turn-off fall time	RG = $6.3\Omega$ , Inductive load			_	500	
trr (Note 1)	Reverse recovery time	IE = 400A		_	_	300	ns
Qrr (Note 1)	Reverse recovery charge			_	16.0	_	μС
VEC(Note 1)	Emitter-collector voltage	IE = 400A, VGE = 0V		_	_	2	V
Rth(j-c)Q	Thermal resistance*1	IGBT part (1/2 module)		_	_	0.14	K/W
Rth(j-c)R	Thermal resistance	FWDi part (1/2 module)		_	_	0.24	
Rth(c-f)	Contact thermal resistance	Case to heat sink, Thermal compound applied*2 (1/2 module)			0.04	_	
Rth(j-c')Q	Thermal resistance*3	Case temperature measured point is just under the chips			_	0.08	

Note 1. IE, IEM, VEC, trr, Qrr & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode (FWDi).



Feb. 2009

<sup>2.</sup> Pulse width and repetition rate should be such that the device junction temperature (Tj) does not exceed Tjmax rating.

3. Junction temperature (Tj) should not increase beyond 150°C.

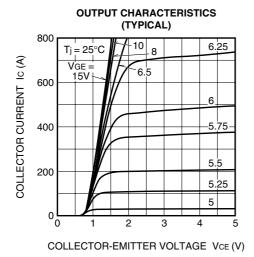
4. Pulse width and repetition rate should be such as to cause negligible temperature rise.

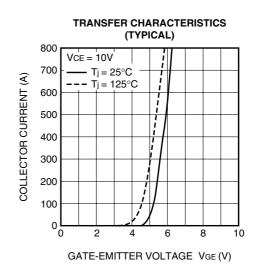
<sup>\*1 :</sup> Case temperature (Tc) measured point is indicated in OUTLINE DRAWING.

<sup>\*2 :</sup> Typical value is measured by using thermally conductive grease of  $\lambda$  = 0.9[W/(m • K)]. \*3 : If you use this value, Rth(f-a) should be measured just under the chips.

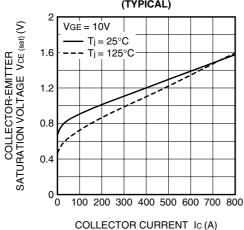
#### **HIGH POWER SWITCHING USE**

#### **PERFORMANCE CURVES**

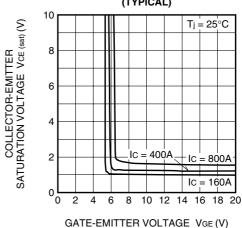




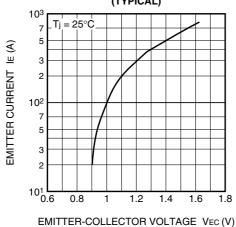
**COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS** (TYPICAL)

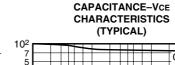


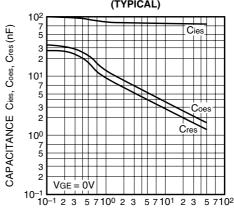




FREE-WHEEL DIODE **FORWARD CHARACTERISTICS** (TYPICAL)







COLLECTOR-EMITTER VOLTAGE VCE (V)

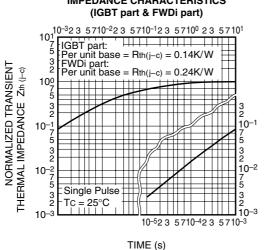


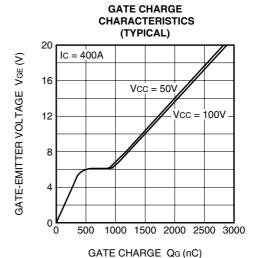
#### **HIGH POWER SWITCHING USE**

#### HALF-BRIDGE **SWITCHING CHARACTERISTICS** (TYPICAL) 10<sup>3</sup> td(off) td(on) 5 - tf – SWITCHING TIMES (ns) 3 tr 2 10<sup>2</sup> 7 Conditions: 5 Vcc = 100V 3 $VGE = \pm 10V$ $RG = 6.3\Omega$ 2 T<sub>i</sub> = 125°C Inductive load 5 7 102 2 3 2 3 COLLECTOR CURRENT Ic (A)

#### REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL) 10<sup>3</sup> REVERSE RECOVERY CURRENT In (A) REVERSE RECOVERY TIME trr (ns) 5 3 2 102 7 Conditions: VCC = 100V $VGE = \pm 10V$ $Rg = 6.3\Omega$ 2 $T_i = 25^{\circ}C$ Inductive load 101 L 101 5 7 102 2 5 7 103 3 2 3 EMITTER CURRENT IE (A)

# TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT part & FWDi part)







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